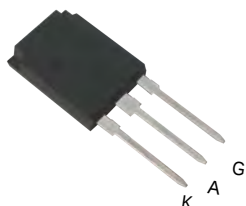
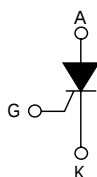


STYN8140

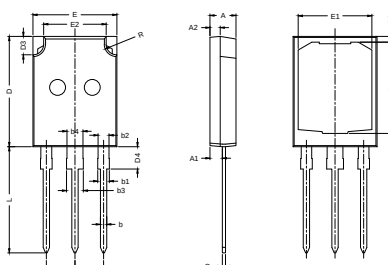
Discrete SCRs (Thyristors)



K=Cathode, A=Anode, G=Gate



Dimensions TO-247P



Dim.	Millimeter		Dim.	Millimeter	
	Min.	Max.		Min.	Max.
A	4.85	5.10	D2	0.96	1.25
A1	2.31	2.51	D3	3.35	3.80
A2	1.85	2.10	D4	3.95	4.45
b	1.16	1.26	E	15.80	16.05
b1	/	2.25	E1	13.50	14.40
b2	1.96	2.15	E2	11.25	12.45
b3	/	3.25			
b4	2.96	3.15	e	5.44(BSC)	
c	0.59	0.66	L	19.80	20.25
D	20.85	21.10			
D1	17.15	17.75	R	1.90	2.10

	VRRM V	VRSM V
STYN8140	800	900

Symbol	Test Conditions	Maximum Ratings	Unit
I_{TRMS} I_{TAVM}	$T_{VJ}=T_{VJM}$ $T_C=85^{\circ}C$; 180° sine	140 90	A
I_{TSM}	$T_{VJ}=45^{\circ}C$ $V_R=0$ $t=10ms$ (50Hz), sine $t=8.3ms$ (60Hz), sine	1700 1800	A
	$T_{VJ}=T_{VJM}$ $V_R=0$ $t=10ms$ (50Hz), sine $t=8.3ms$ (60Hz), sine	1540 1640	
I^2t	$T_{VJ}=45^{\circ}C$ $V_R=0$ $t=10ms$ (50Hz), sine $t=8.3ms$ (60Hz), sine	11450 13500	A^2s
	$T_{VJ}=T_{VJM}$ $V_R=0$ $t=10ms$ (50Hz), sine $t=8.3ms$ (60Hz), sine	11850 11300	
$(di/dt)_{cr}$	$T_{VJ}=T_{VJM}$ $f=50Hz$, $t_p=200\mu s$ $V_D=2/3V_{DRM}$ $I_G=0.45A$ $di_G/dt=0.45A/\mu s$ repetitive, $I_T=250A$	150	A/ μs
	non repetitive, $I_T=I_{TAVM}$	500	
$(dv/dt)_{cr}$	$T_{VJ}=T_{VJM}$; $V_{DR}=2/3V_{DRM}$ $R_{GK}=\infty$; method 1 (linear voltage rise)	1000	V/ μs
P_{GM}	$T_{VJ}=T_{VJM}$ $I_T=I_{TAVM}$ $t_p=30\mu s$ $t_p=300\mu s$	10 5	W
P_{GAV}		0.5	W
V_{RGM}		10	V
T_{VJ} T_{VJM} T_{stg}		-40...+140 140 -40...+125	$^{\circ}C$
M_d F_c	Mounting torque (M3) Mounting force with clip	0.8...1.2 20...120	Nm N
Weight	typical	6	g

Sirectifier®

STYN8140

Discrete SCRs (Thyristors)

Symbol	Test Conditions	Characteristic Values		Unit
		STYN8140-16140	STYN18140-22140	
I_R, I_D	$T_{VJ}=T_{VJM}; V_R=V_{RRM}; V_D=V_{DRM}$	5		mA
V_{TM}	$I_T=270A; T_{VJ}=25^{\circ}C$	1.60	1.90	V
V_{TO}	For power-loss calculations only ($T_{VJ}=125^{\circ}C$)	0.85		V
r_T		2.70	3.80	m Ω
V_{GT}	$V_D=6V; T_{VJ}=25^{\circ}C$ $T_{VJ}=-40^{\circ}C$	1.5 1.6		V
I_{GT}	$V_D=6V; T_{VJ}=25^{\circ}C$ $T_{VJ}=-40^{\circ}C$	100 200		mA
V_{GD}	$T_{VJ}=T_{VJM}; V_D=2/3V_{DRM}$	0.2		V
I_{GD}		10		mA
I_L	$T_{VJ}=25^{\circ}C; t_p=10\mu s;$ $I_G=0.3A; di_G/dt=0.3A/\mu s$	150		mA
I_H	$T_{VJ}=25^{\circ}C; V_D=6V; R_{GK}=\infty$	100		mA
t_{gd}	$T_{VJ}=25^{\circ}C; V_D=1/2V_{DRM}$ $I_G=0.3A; di_G/dt=0.3A/\mu s$	2		μs
R_{thJC}	DC current	0.16		K/W
R_{thJH}	DC current	typ.	0.10	K/W
a	Max. acceleration, 50 Hz	50		m/s ²

Features / Advantages:

- Thyristor for line frequency
- Glass passivated chip

Product Reliability

- IEC147-4
- IEC68-2-14
- IEC68-2-20
- IEC68-2-27
- CECC50000-4.4.3

Package: TO-247AD

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control



ORDERING INFORMATION

Part Number	Package	Shipping	Marking Code
STYN8140	TO-247P	30pcs / Tube	STYN8140

Packing: 30pcs per tube, 20 tubes per box (=600pcs) , 6 boxes per carton (=3600pcs)

STYN8140

Discrete SCRs (Thyristors)

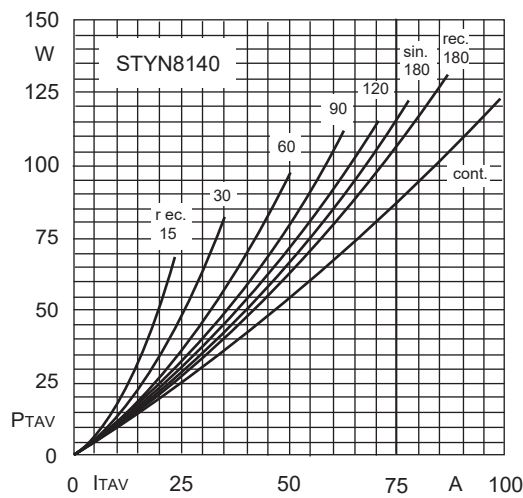


Fig.1 Power dissipation per thyristor vs. on-state current

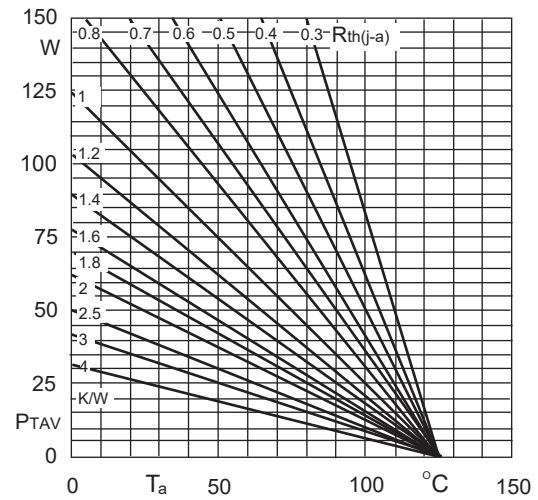


Fig. 2 Power dissipation per thyristor vs. ambient temp

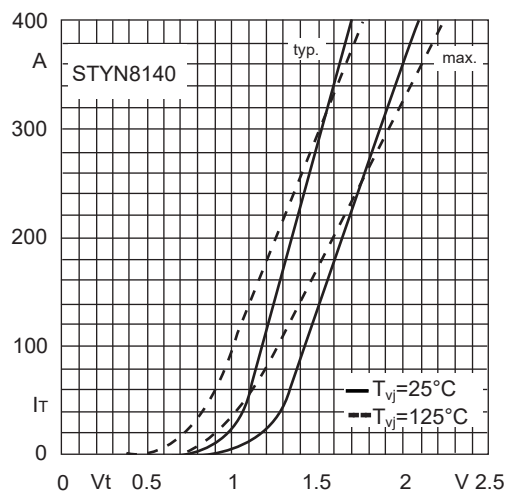


Fig.3 On-state characteristics

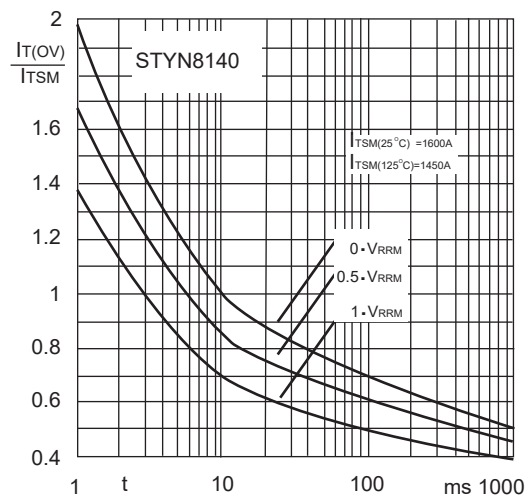


Fig.4 Surge overload current vs. time